

GPS LOW NOISE AMPLIFIER GaAs MMIC

■ GENERAL DESCRIPTION

The NJG1143UA2 is a GPS LNA GaAs MMIC featured very small size, low noise figure, high gain and low current consumption. The NJG1143UA2 operates from 1.5V to 3.6V single voltage, has stand-by mode to save the supply current, and requires only three external components. The NJG1143UA2 has a on-chip ESD protection. The NJG1143UA2 is available in a very small, lead-free, halogen-free, 1.0mm x 1.0mm x 0.37 mm, 6-pin EPFFP6-A2 package.

■ PACKAGE OUTLINE

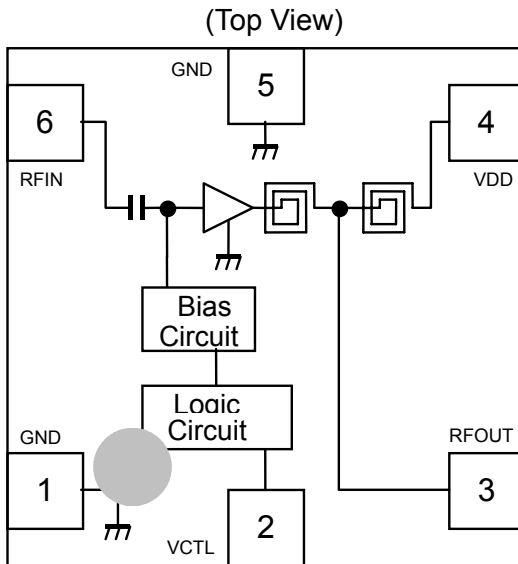


NJG1143UA2

■ FEATURES

- Low supply voltage +2.85V typ. (+1.5V~+3.6V)
- Low control voltage +1.8V typ. (+1.5V~+3.6V)
- Low current consumption 4.0mA typ. @V_{DD}=2.85V, V_{CTL}=1.8V
- 7μA typ. @V_{DD}=2.85V, V_{CTL}=0V, Stand-by mode
- High gain 20.0dB typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- Low noise figure 0.70dB typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- Input power at 1dB gain compression point -16.5dBm typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575MHz
- High input IP3 -2.0dBm typ. @V_{DD}=2.85V, V_{CTL}=1.8V, f=1575+1575.1MHz
- Stand-by function
- Small package size EPFFP-A2 (Package size: 1.0mmx1.0mmx0.37mm typ.)
- Integrated ESD protection circuit
- Lead-free and halogen-free

■ PIN CONFIGURATION



- Pin Connection
1. GND
 2. VCTL
 3. RFOUT
 4. VDD
 5. GND
 6. RFIN

■ TRUTH TABLE

“H”=V_{CTL}(H), “L”=V_{CTL}(L)

VCTL	LNA Mode
H	Active mode
L	Stand-by mode

Note: Specifications and description listed in this datasheet are subject to change without notice.

NJG1143UA2

■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$, $Z_s=Z_i=50\Omega$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Control voltage	V_{CTL}		5.0	V
Input power	P_{IN}	$V_{DD}=2.85\text{V}$	+15	dBm
Power dissipation	P_D	4-layer FR4 PCB with through-hole (101.5mmx114.5mm), $T_i=150^{\circ}\text{C}$	590	mW
Operating temperature	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55~+150	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions: $T_a=+25^{\circ}\text{C}$, $Z_s=Z_i=50\Omega$)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{DD}	VDD Terminal	1.5	-	3.6	V
Control Voltage (High)	$V_{CTL(H)}$	VCTL Terminal	1.5	1.8	3.6	V
Control Voltage (Low)	$V_{CTL(L)}$	VCTL Terminal	0	0	0.3	V
Supply Current 1	I_{DD1}	Active mode VDD Terminal $V_{DD}=2.85\text{V}$, $V_{CTL}=1.8\text{V}$	-	4.0	6.5	mA
Supply Current 2	I_{DD2}	Active mode VDD Terminal $V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	3.0	4.7	mA
Supply Current 3	I_{DD3}	Stand-by mode VDD Terminal $V_{DD}=2.85\text{V}$, $V_{CTL}=0\text{V}$	-	7.0	15.0	μA
Supply Current 4	I_{DD4}	Stand-by mode VDD Terminal $V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	-	4.0	10.0	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$, VCTL Terminal	-	5.0	12.0	μA

■ ELECTRICAL CHARACTERISTICS 2 (RF, $V_{DD}=2.85V$)

(General conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, Freq=1.575GHz, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 1	Gain1		17.5	20.0	22.0	dB
Noise Figure 1	NF1	Exclude PCB and connector Losses (0.08dB)	-	0.70	0.95	dB
Input Power at 1dB Gain Compression Point 1	P-1dB(IN) _1		-19.0	-16.5	-	dBm
Input 3rd Order Intercept Point 1	IIP3_1	f1=Freq f2=Freq+100kHz Pin=-34dBm	-6.0	-2.0	-	dBm
RF Input Port VSWR 1	VSWR _i 1		-	1.5	2.0	
RF Output Port VSWR 1	VSWR _o 1			1.5	2.0	

■ ELECTRICAL CHARACTERISTICS 3 (RF, $V_{DD}=1.8V$)

(General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, Freq=1.575GHz, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 2	Gain2		16.5	19.0	21.0	dB
Noise Figure 2	NF2	Exclude PCB and connector Losses (0.08dB)	-	0.75	1.10	dB
Input Power at 1dB Gain Compression Point 2	P-1dB(IN) _2		-22.0	-19.5	-	dBm
Input 3rd Order Intercept Point 2	IIP3_2	f1=Freq f2=Freq+100kHz Pin=-34dBm	-10.0	-6.0	-	dBm
RF Input Port VSWR 2	VSWR _i 2		-	1.5	2.3	
RF Output Port VSWR 2	VSWR _o 2			1.3	1.7	

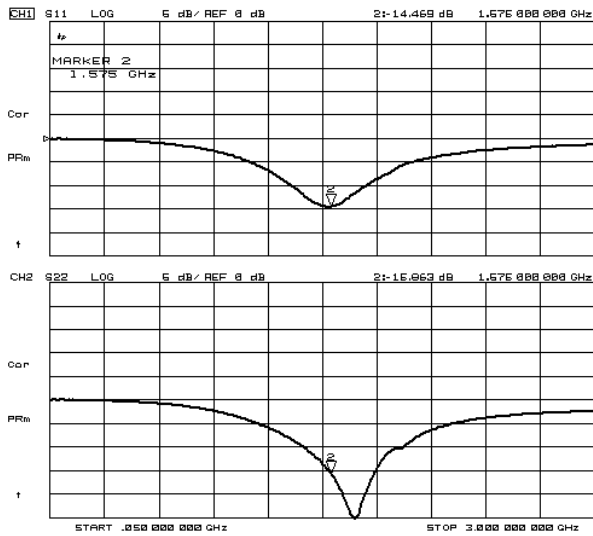
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■ TERMINAL INFORMATION

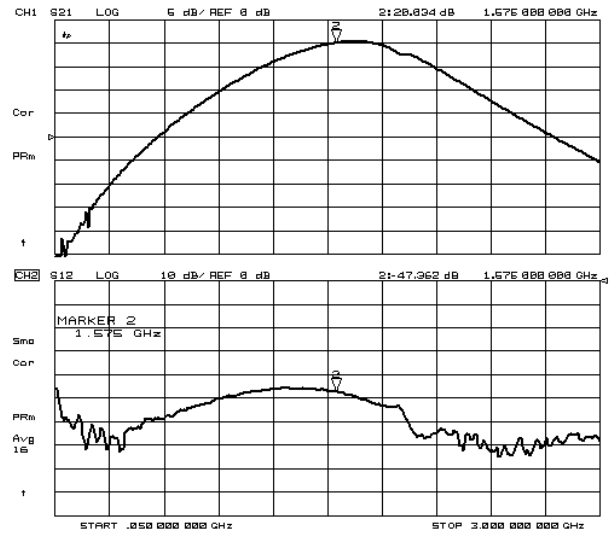
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
2	VCTL	Control voltage terminal. Inputting a logic-high, the LNA turn at LNA active mode. Inputting a logic-low, the LNA turn at stand-by mode.
3	RFOUT	RF output terminal. Requires an external capacitor C1. The capacitor C1 is not only a matching component , but also a DC blocking capacitor.
4	VDD	Supply voltage terminal. Bypass to ground with capacitor C2 as close as possible to the IC.
5	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
6	RFIN	RF input terminal. Requires a matching inductor L1. Integrated a DC blocking capacitor.

ELECTRICAL CHARACTERISTICS

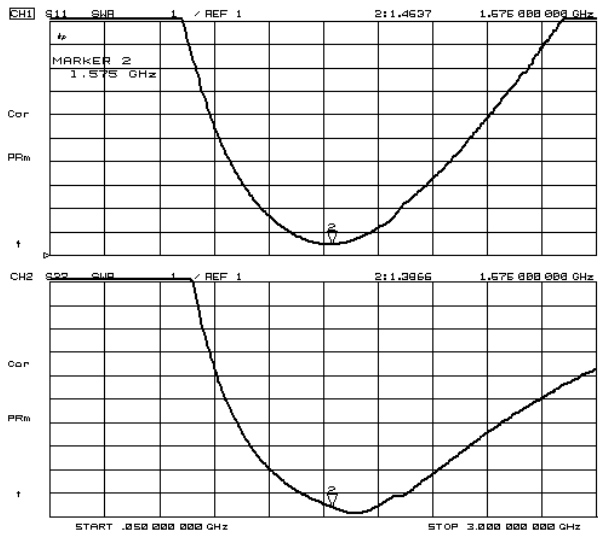
Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



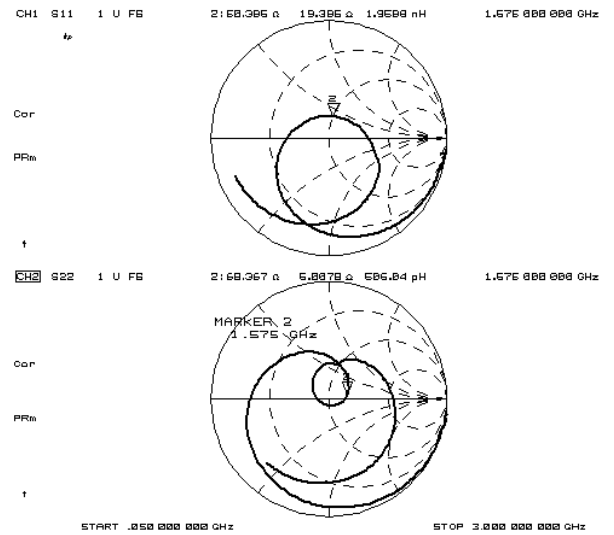
S11, S22



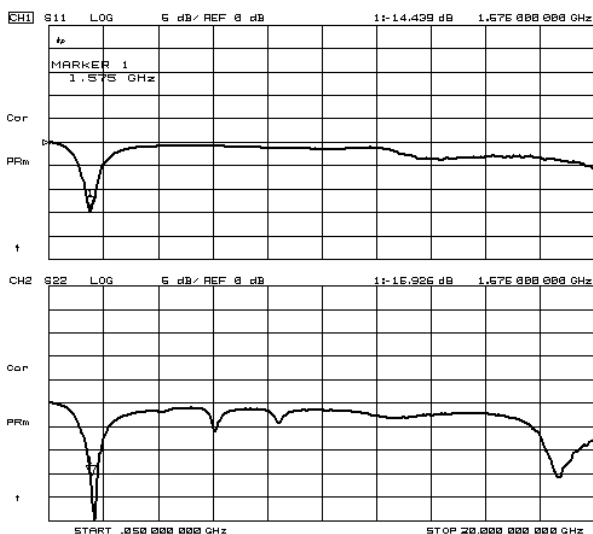
S21, S12



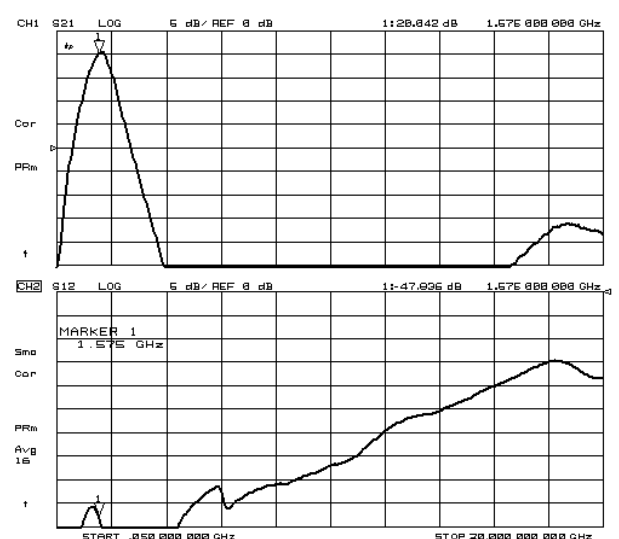
VSWR



Zin, Zout



S11, S22 (f=50MHz~20GHz)

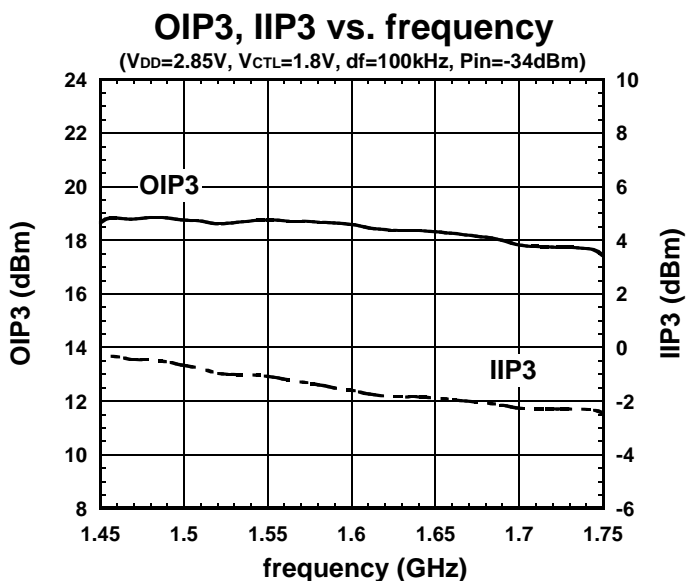
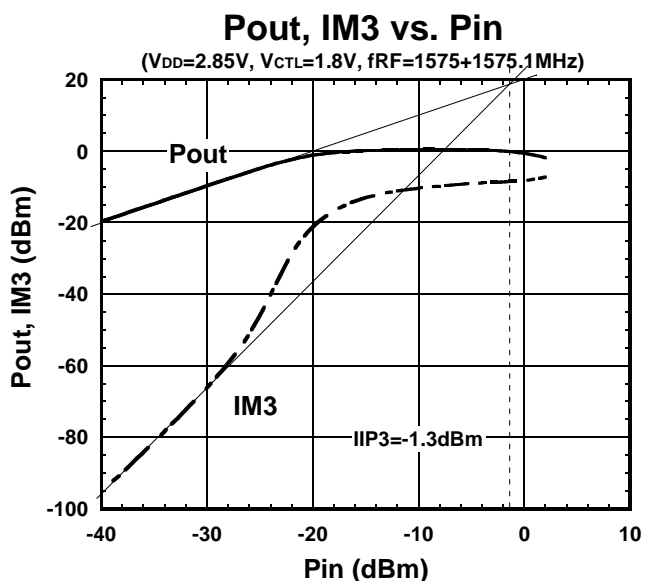
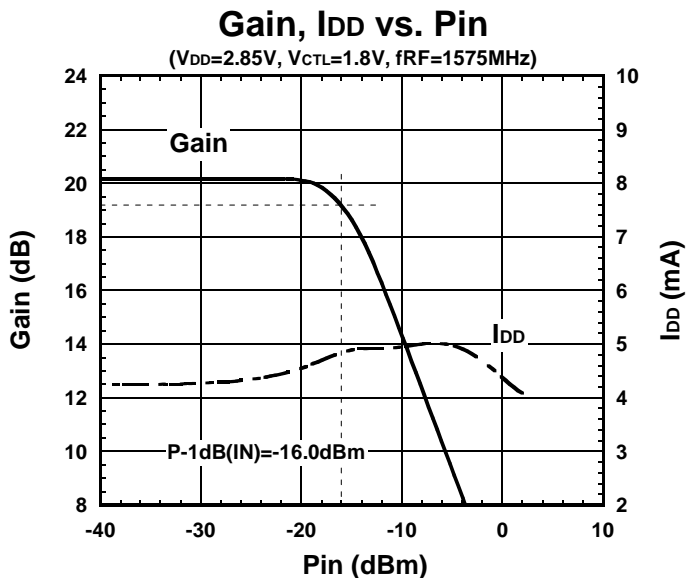
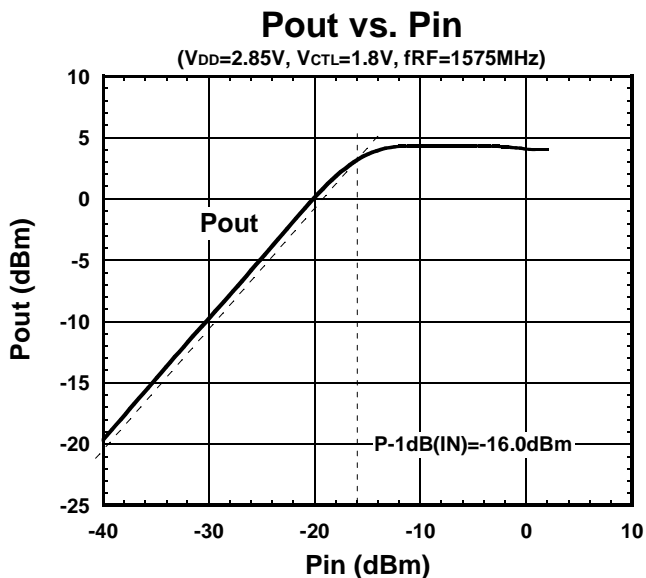
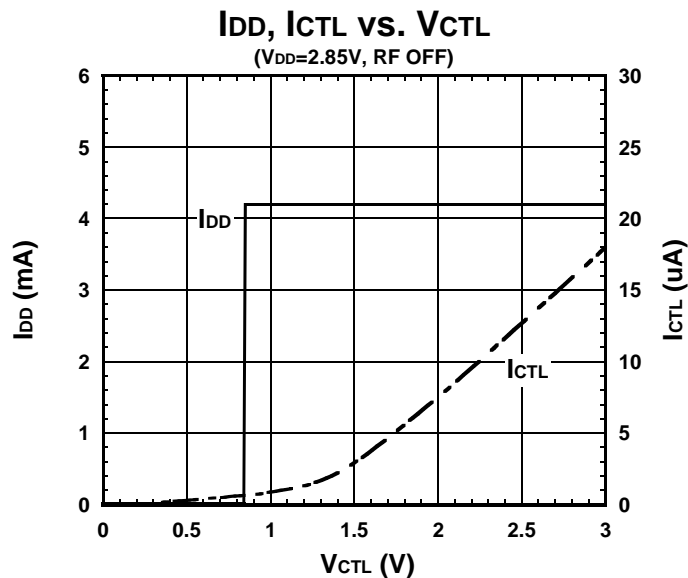
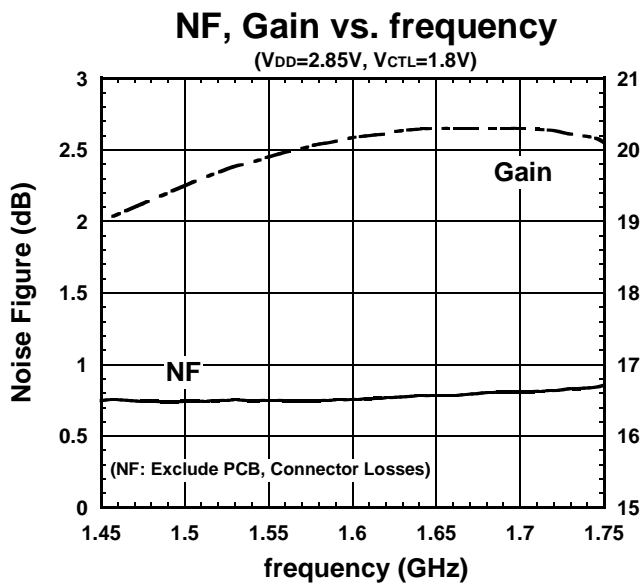


S21, S12 (f=50MHz~20GHz)

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ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

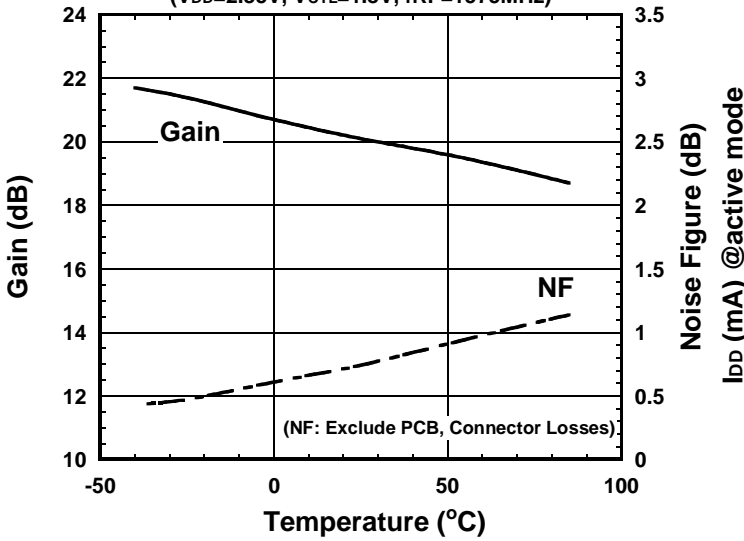


ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.85V$, $V_{CTL}=1.8V$, $T_a=+25^\circ C$, $Z_s=Z_l=50\Omega$, with application circuit

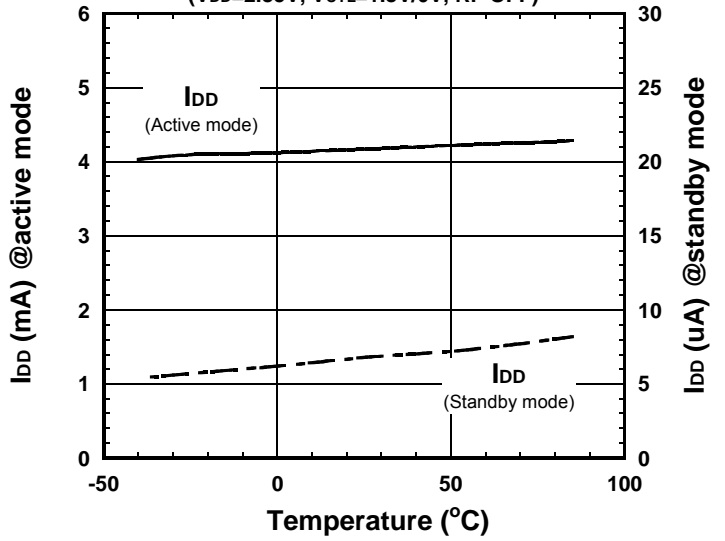
Gain, NF vs. Temperature

($V_{DD}=2.85V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



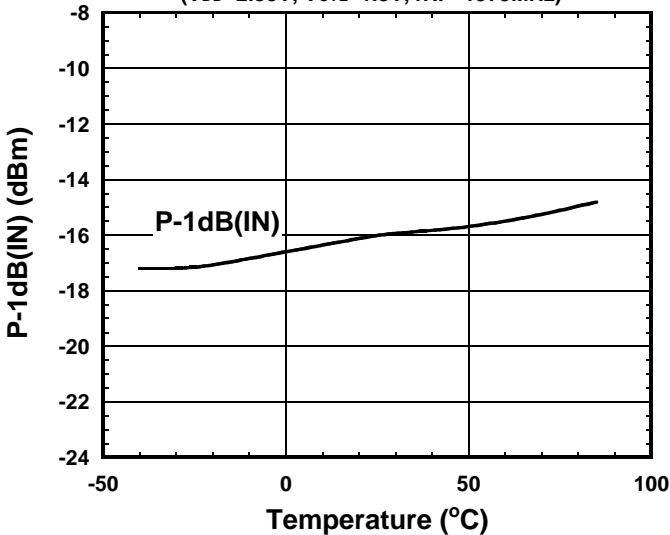
I_{DD} vs. Temperature

($V_{DD}=2.85V$, $V_{CTL}=1.8V/0V$, RF OFF)



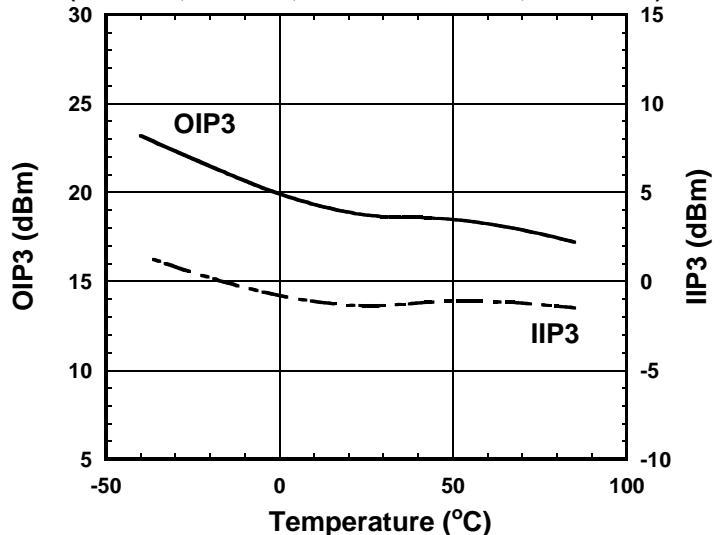
P-1dB(IN) vs. Temperature

($V_{DD}=2.85V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



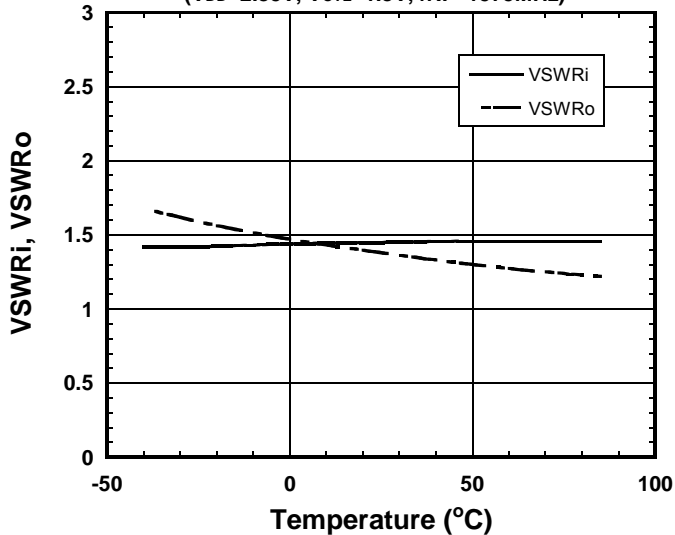
OIP3, IIP3 vs. Temperature

($V_{DD}=2.85V$, $V_{CTL}=1.8V$, $f_{RF}=1575+1575.1MHz$, $P_{in}=-34dBm$)



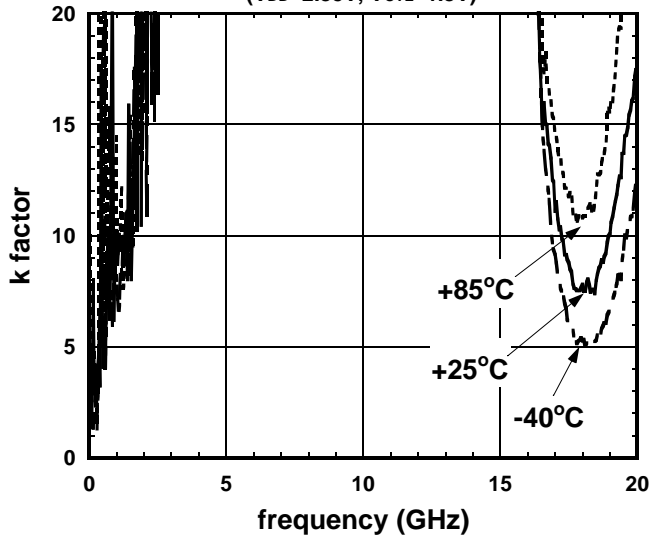
VSWR vs. Temperature

($V_{DD}=2.85V$, $V_{CTL}=1.8V$, $f_{RF}=1575MHz$)



k factor vs. frequency

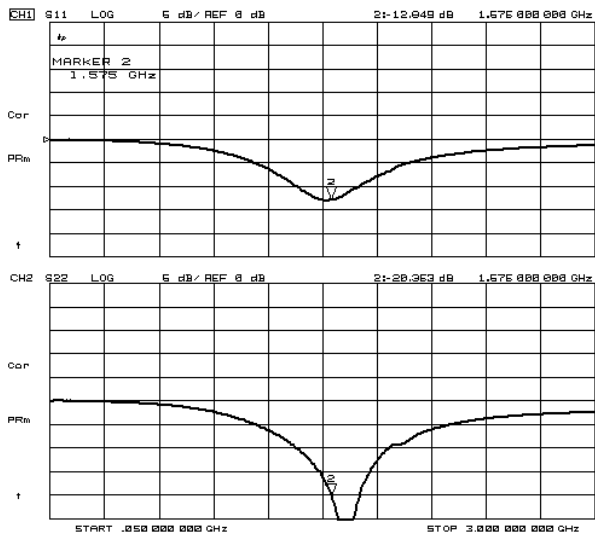
($V_{DD}=2.85V$, $V_{CTL}=1.8V$)



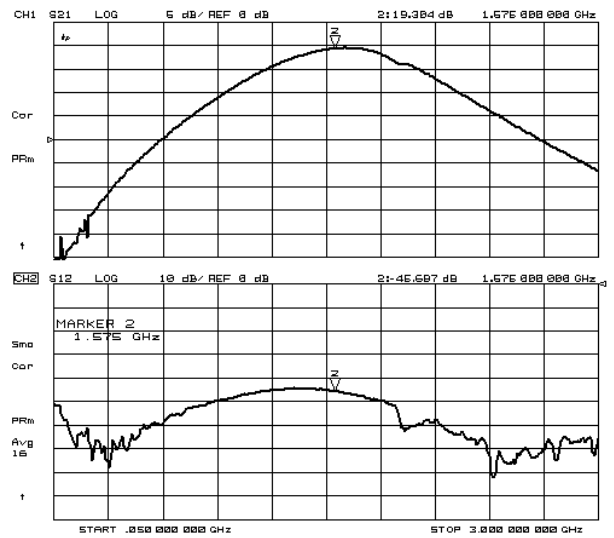
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ELECTRICAL CHARACTERISTICS

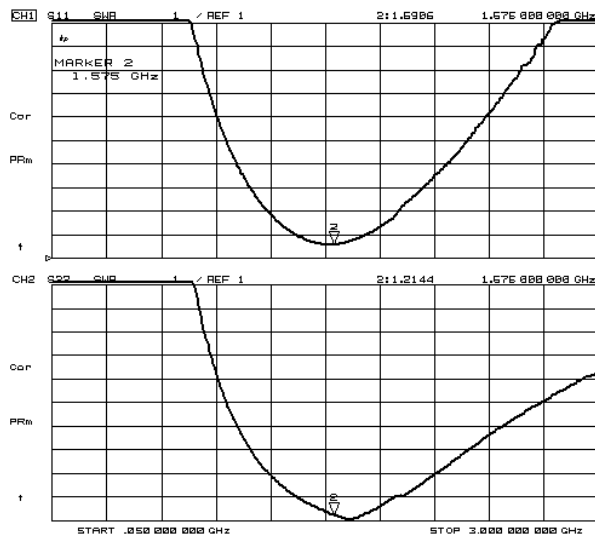
Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit



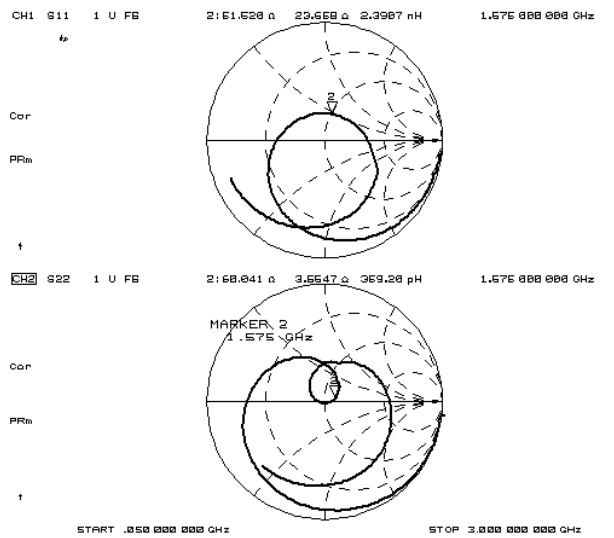
S11, S22



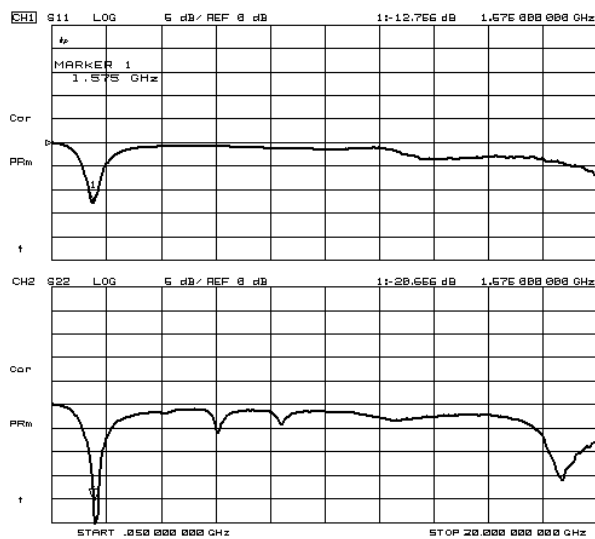
S21, S12



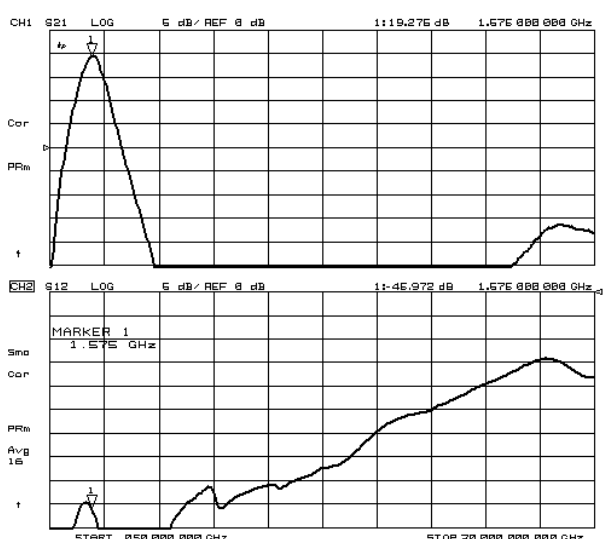
VSWR



Zin, Zout



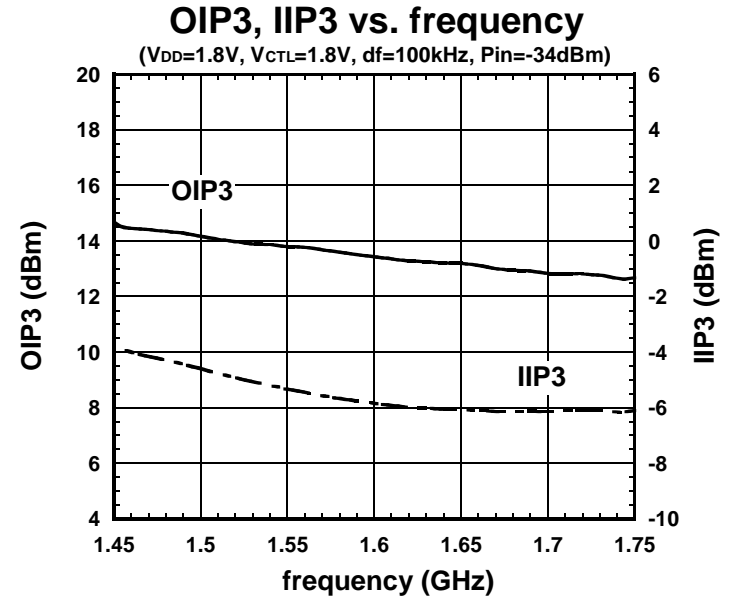
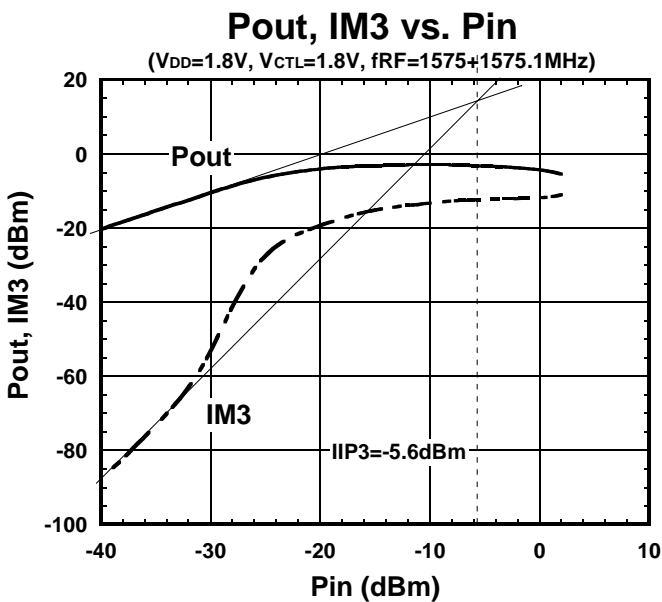
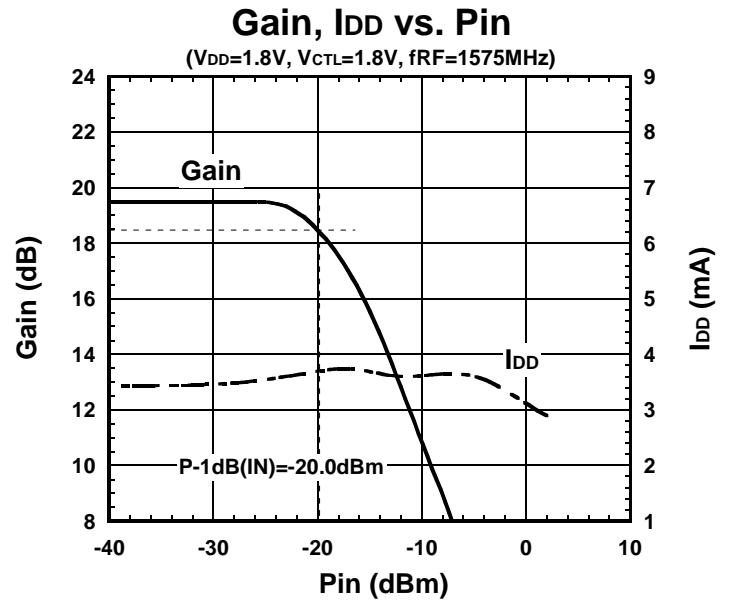
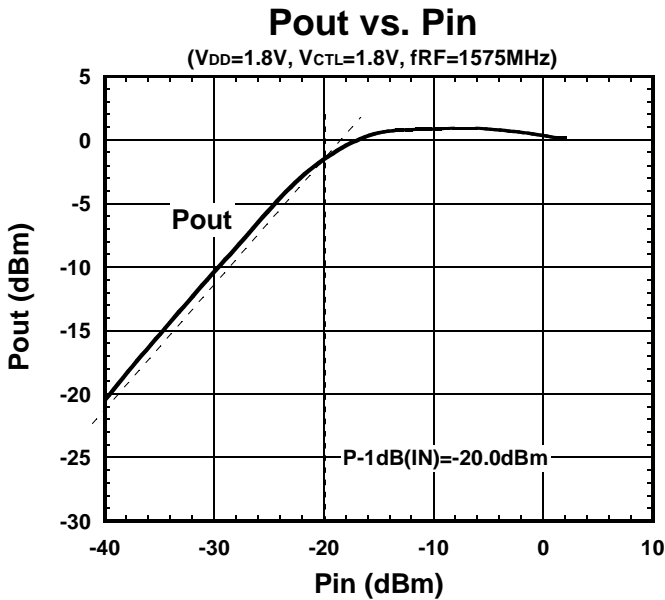
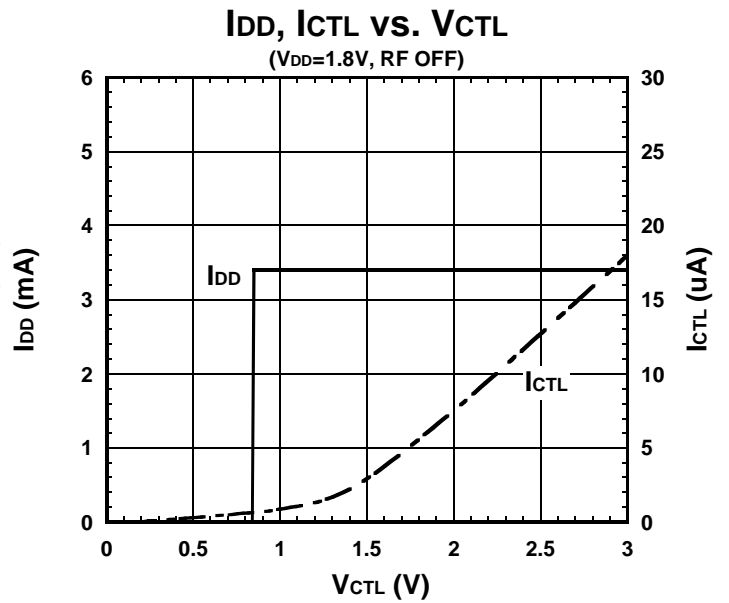
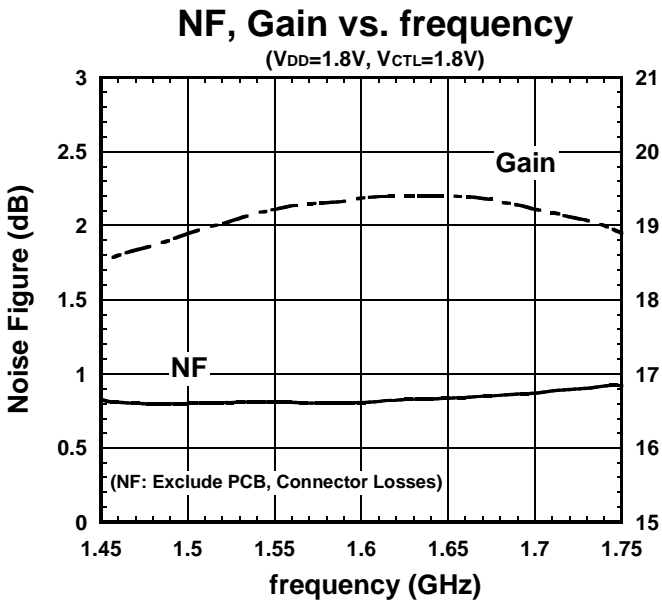
S11, S22 (f=50MHz~20GHz)



S21, S12 (f=50MHz~20GHz)

ELECTRICAL CHARACTERISTICS

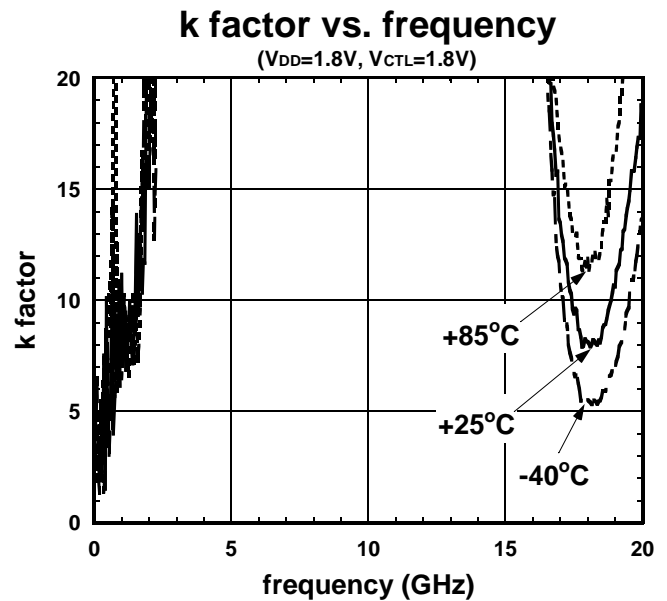
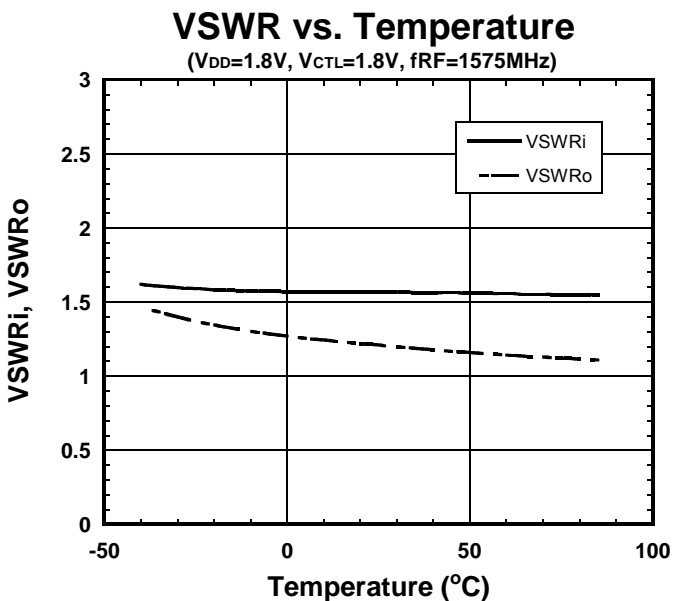
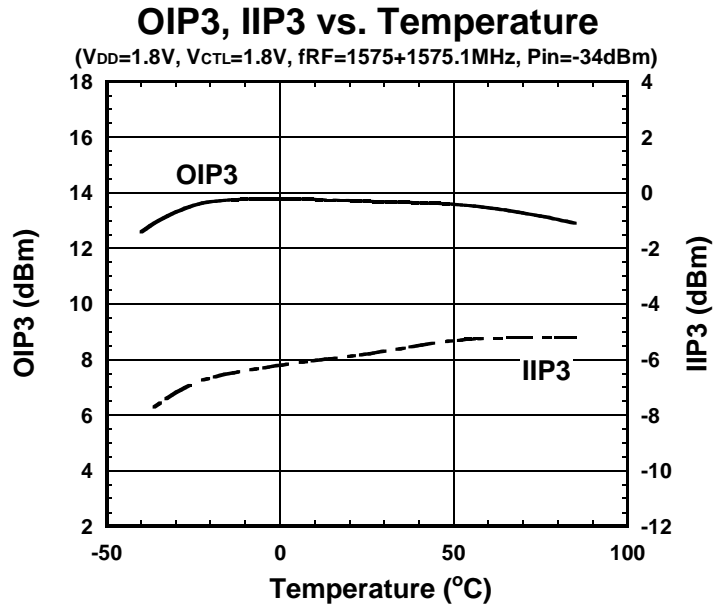
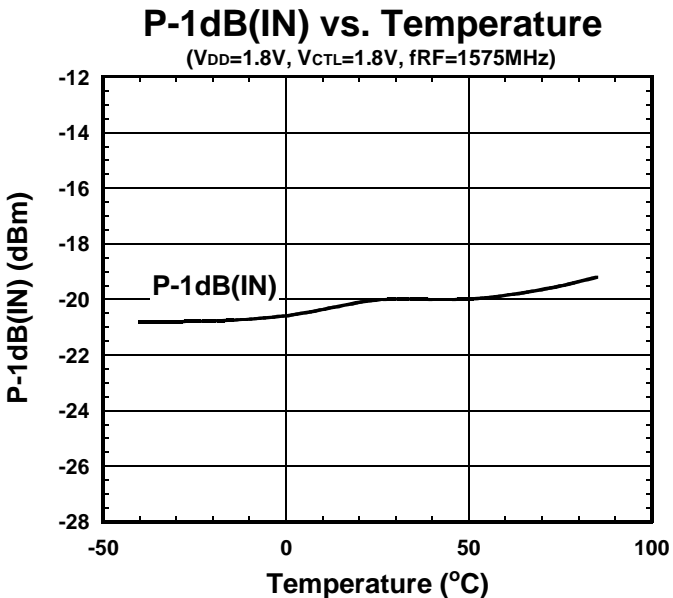
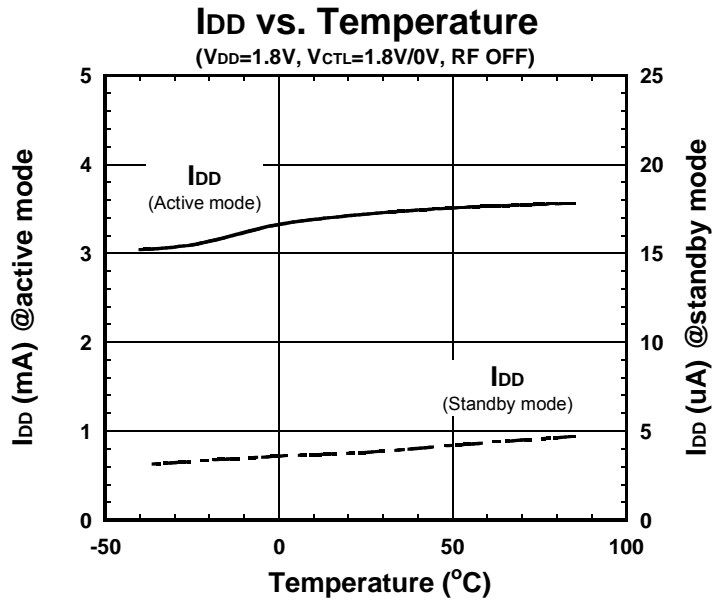
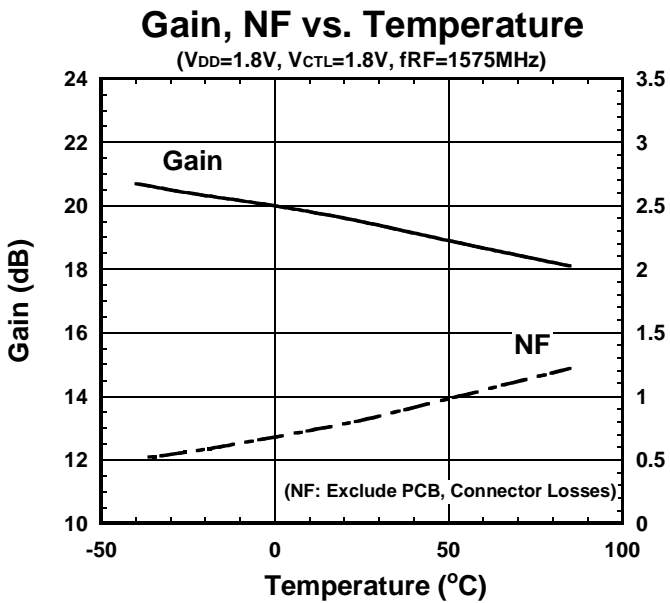
Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=+25^\circ C$, $Z_s=Z_l=50\Omega$, with application circuit



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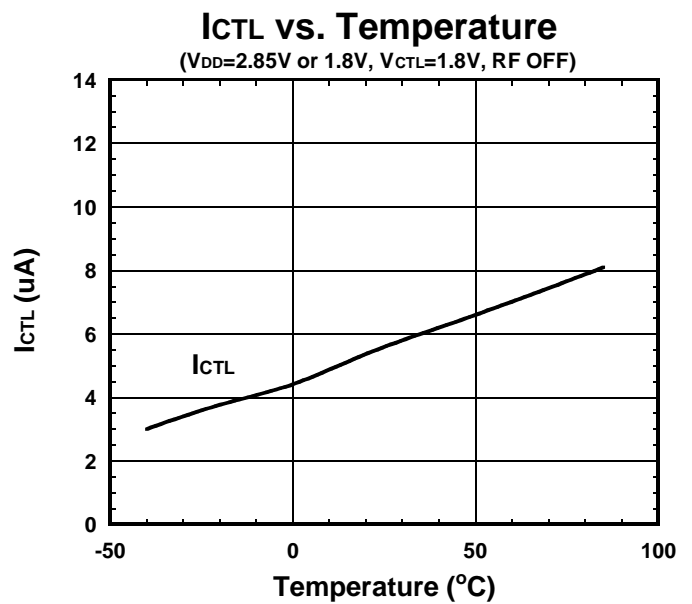
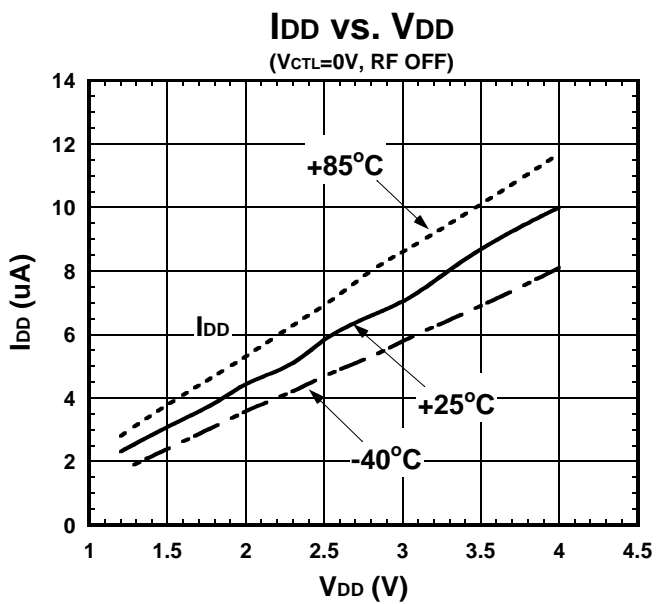
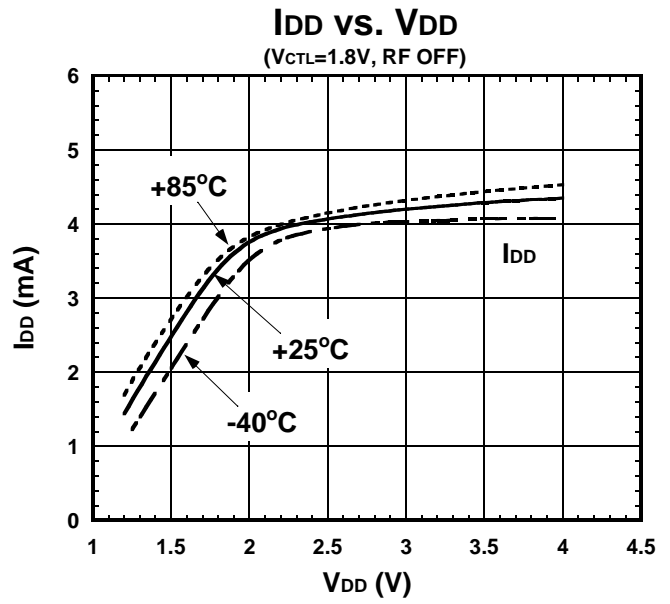
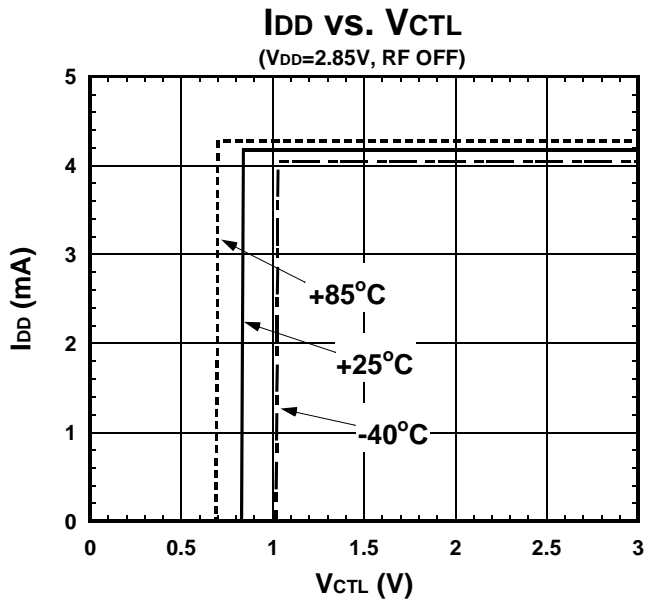
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $Z_S=Z_I=50\Omega$, with application circuit



■ ELECTRICAL CHARACTERISTICS

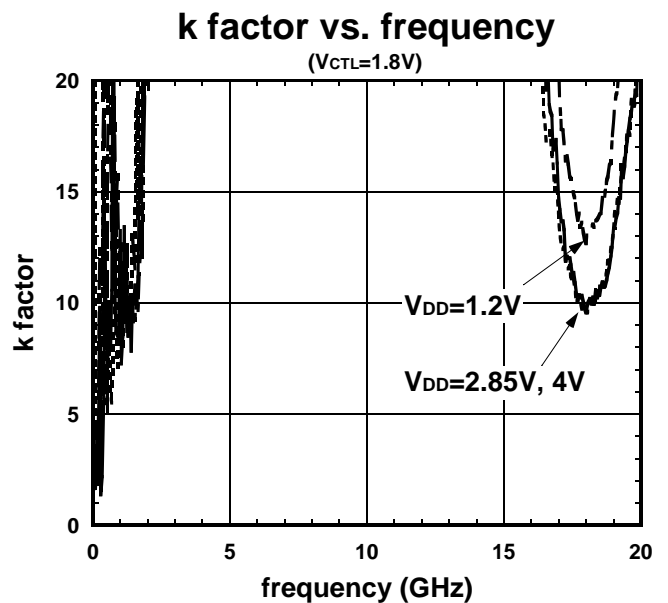
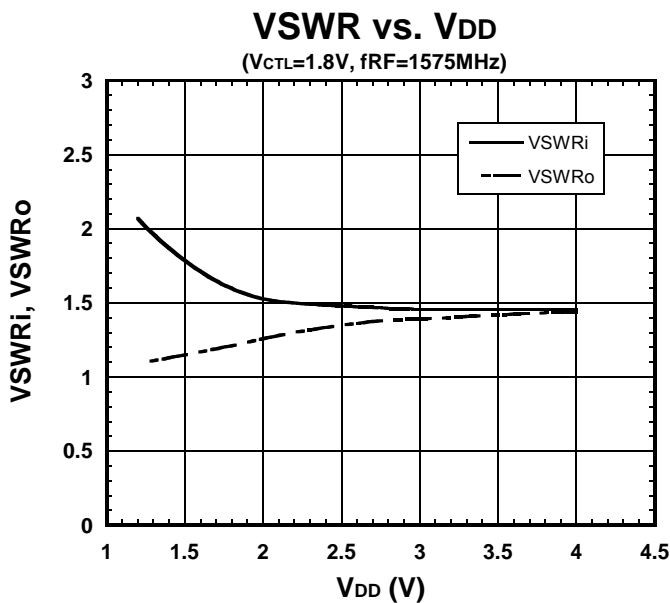
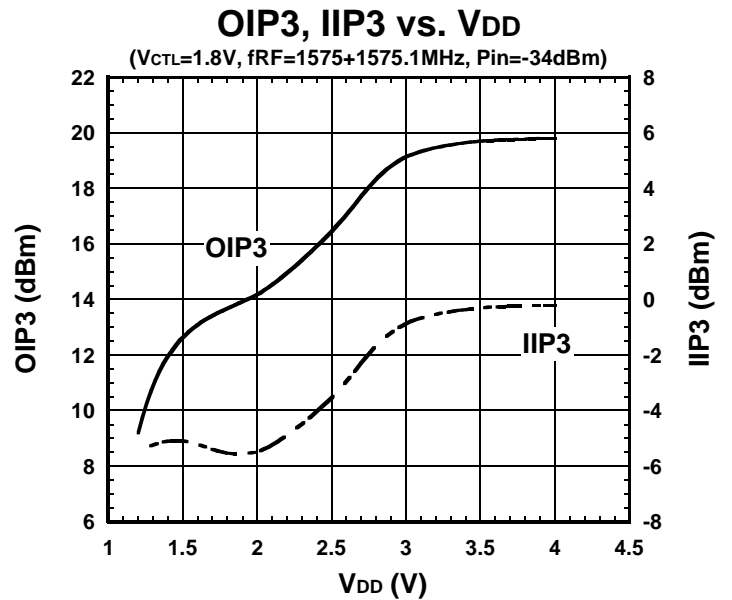
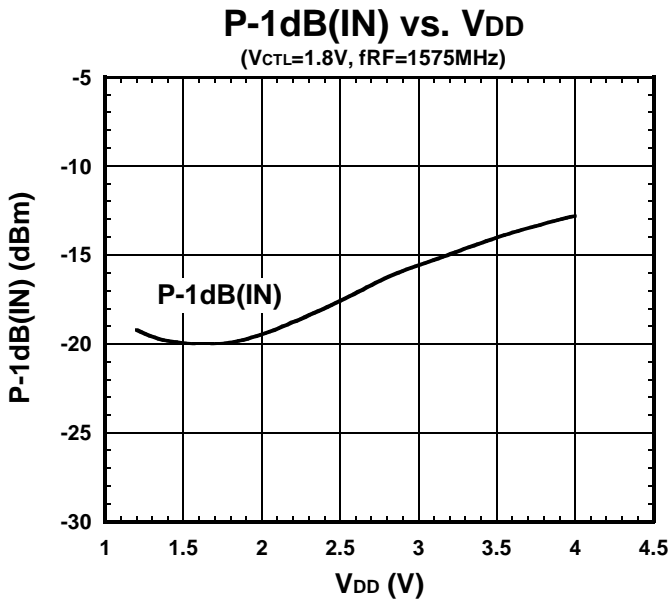
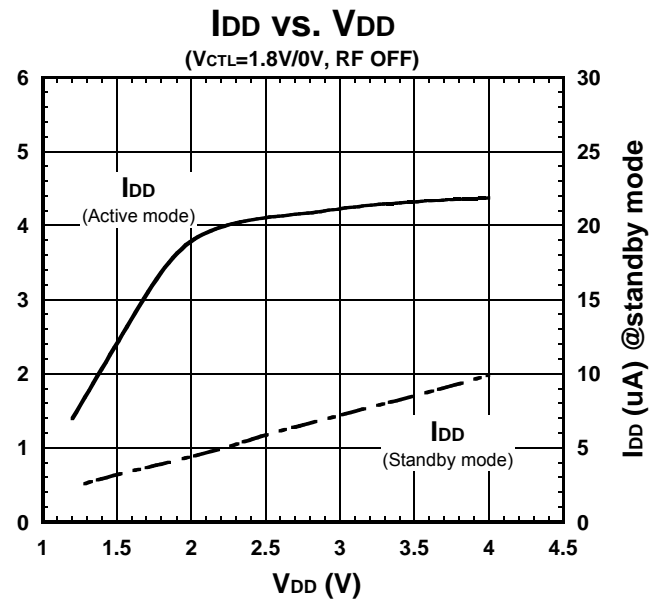
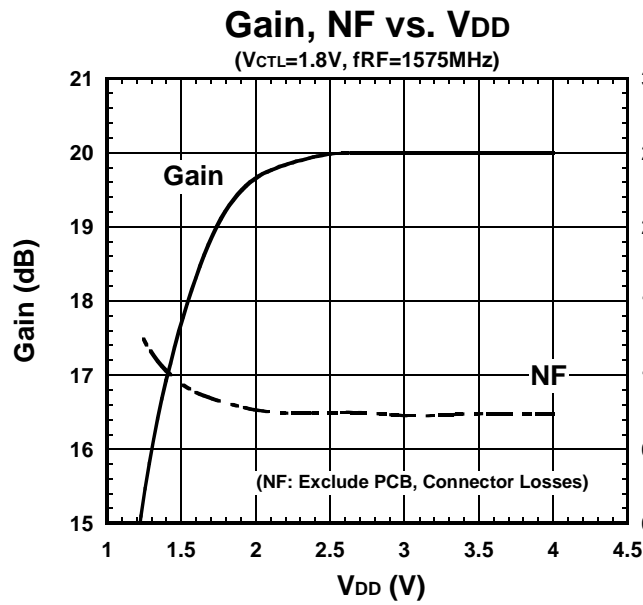
Conditions: RF OFF, $Z_s=Z_l=50\Omega$, with application circuit



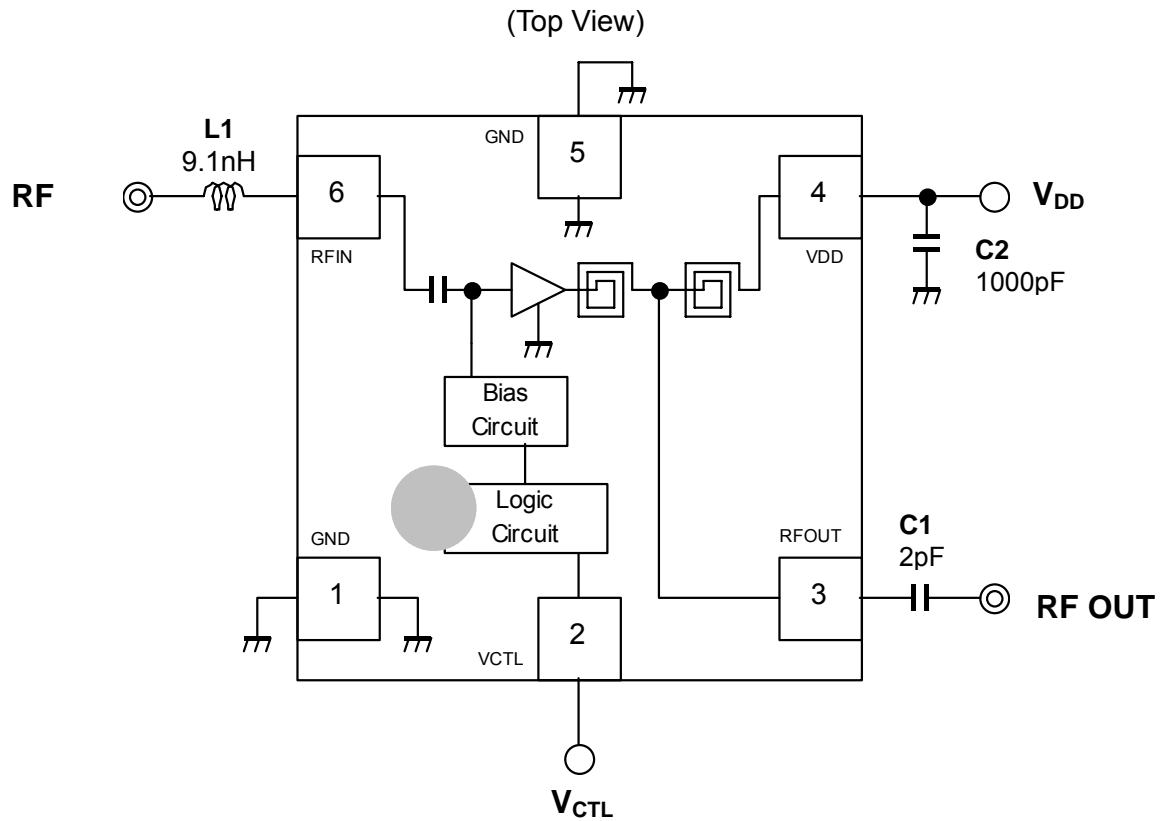
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ELECTRICAL CHARACTERISTICS

Condition: $V_{CTL}=1.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit

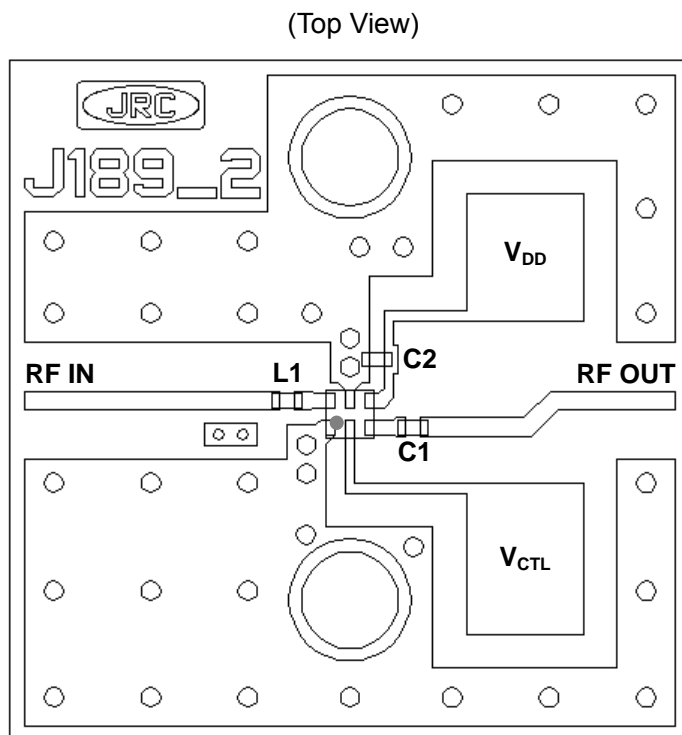


APPLICATION CIRCUIT



- L1 is an input matching inductor.
- C1 is an output matching capacitor and a DC blocking capacitor.
- C2 is a bypass capacitor.

TEST PCB LAYOUT



Parts list

Parts ID	Manufacture
L1	LQP03T_02 Series (MURATA)
C1, C2	GRM03 Series (MURATA)

PCB

Substrate: FR-4
 Thickness: 0.2mm
 Microstrip line width: 0.4mm ($Z_0=50\Omega$)
 Size: 14.0mm x 14.0mm

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■ NOISE FIGURE MEASUREMENT CONDITONS

Measuring instruments

NF Analyzer : Agilent 8973A, 8975A

Noise Source : Agilent 346A

Setting the NF analyzer

Measurement mode form

Device under test : Amplifier

System downconverter : off

Mode setup form

Sideband : LSB

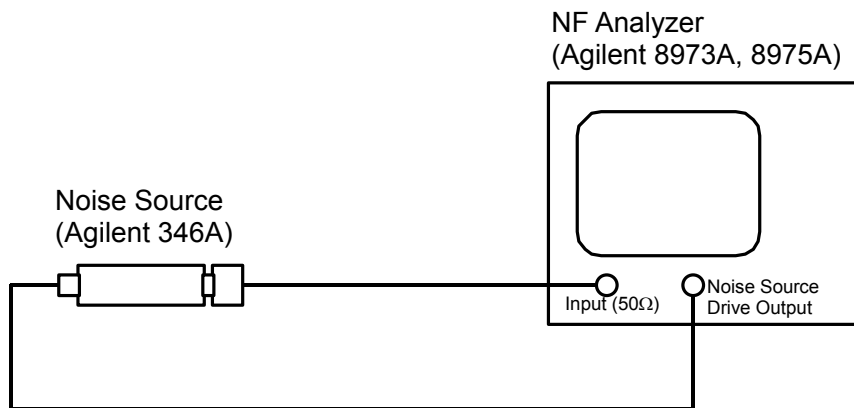
Averages : 16

Average mode : Point

Bandwidth : 4MHz

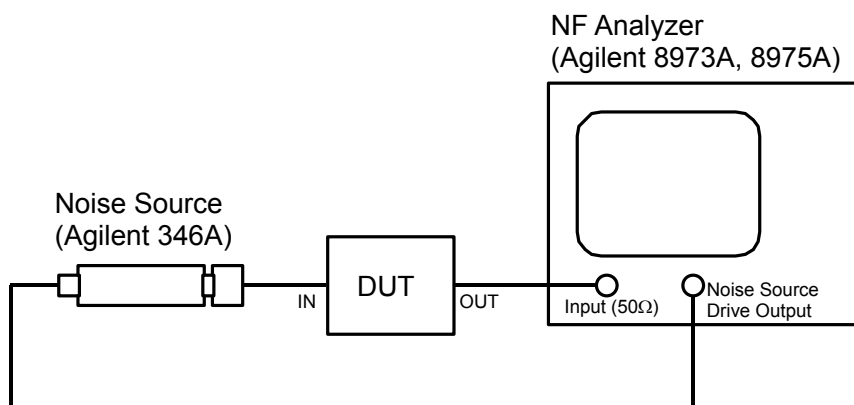
Loss comp : off

Tcold : setting the temperature of noise source (303.15K)



* Noise source and NF analyzer are connected directly.

Calibration Setup



* Noise source and DUT, DUT and NF analyzer are connected directly.

Measurement Setup

